### OPB827, OPB828, OPB829Z Series

# COPB827 OPB828 OPB828 OPB828 OPB829Z

#### Features:

- 0.125" (3.18 mm) wide, 0.315" (8.00 mm) deep slot
- 0.305" (7.75 mm) lead spacing (OPB827)
- 0.220" (5.59 mm) lead spacing (OPB828)
- 24-inch 26 AWG wire leads (OPB829)
- Inexpensive plastic housing

#### **Description:**

Each **OPB827**, **OPB828** and **OPB829** device consists of an infrared emitting diode (LED, 890 nm center wavelength) and a NPN silicon phototransistor, mounted on opposite sides of a 0.125" (3.18 mm) wide slot in a low-cost black plastic housing. A variety of aperture sizes are offered (see chart below). The **OPB827** and **OPB828** are designed fro PCBoard mounting with a minimum lead length of 0.35" (8.9 mm) while the **OPB829Z** (wire version) has 24-inch 26 AWG wire leads. Phototransistor switching occurs when an opaque object passes through the slot.

The **OPB827** is offered with 0.305" (7.75 mm) and the **OPB828** is offered with 0.220" (5.59 mm) lead spacing for PCBoard mounting. The **OPB829Z** has 24" (61 cm) 26 AWG wire leads for remote mounting.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

#### **Applications:**

- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment safety
- Machine safety

Ordering Information								
Part Number	Slot Width/Depth	Housing	Aperture Emitter/Sensor	Wire Lead Length / Spacing				
OPB827A		IR Transmissive	None					
OPB827B	0 120" (0 215"	ik iransmissive	None / 0.01"					
OPB827C	0.120" / 0.315"	0	None / 0.06"	0.425" / 0.300"				
OPB827D		Opaque	None / 0.01"					
OPB828A			None					
OPB828B	0 120" (0 215"	IR Transmissive	None / 0.01"	0 425" ( 0 220"				
OPB828C	0.120" / 0.315"	0	None / 0.06"	0.425" / 0.220"				
OPB828D		Opaque	None / 0.01"					
OPB829AZ			None					
OPB829BZ	0 125" (0 215"	IR Transmissive	None / 0.01"	24" / 26 AWG Wire				
OPB829CZ	0.125" / 0.315"	0	None / 0.06"					
OPB829DZ		Opaque	None / 0.01"					



CONTAINS POLYSULFONE To avoid stress cracking, we suggest using ND Industries' Vibra-Tite for thread-locking.

ND Industries' Vibra-Tite for thread-locking. Vibra-Tite evaporates fast without causing structural failure in OPTEK's molded plastics. Applies to: OPB360, OPB370, OPB380, OPB390 and OPB860, OPB870, OPB880, OPB890.

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

### OPB827, OPB828, OPB829Z Series



### **Electrical Specifications**

#### Absolute Maximum Ratings (T<sub>A</sub> = 25° C unless otherwise noted)

Storage and Operating Temperature OPB827, OPB828 OPB829Z	-40° C to +85° C -40° C to +80° C	
Lead Soldering Temperature (1/16 inch [1.6 mm] from case for 5 seconds with soldering iron) $^{(1)}$	260° C	
put Diode		
Forward DC Current	50 mA	
Peak Forward Current (1µs pulse width, 300 pps)	3 A	
Reverse DC Voltage	2 V	
Power Dissipation <sup>(2)</sup>	100 mW	

#### output i nototransistor

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	30 mA
Power Dissipation <sup>(2)</sup>	100 mW

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

(2) Derate linearly 1.82 mW/° C above 25° C.

(3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.

(4) All parameters were tested using pulse technique.

#### Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	ΜΑΧ	UNITS	TEST CONDITIONS		
Input Diode (See OP240 for additional information—for reference only)								
V <sub>F</sub>	Forward Voltage	-	-	1.7	V	I <sub>F</sub> = 20 mA		
I <sub>R</sub>	Reverse Current	-	-	100	μA	V <sub>R</sub> = 2 V		
Output Transistor (See OP550 for additional information—for reference only)								
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	30	-	-	V	I <sub>c</sub> = 1 mA		
V <sub>(BR)ECO</sub>	Emitter-Collector Breakdown Voltage	5	-	-	V	I <sub>E</sub> = 100 μA		
I <sub>CEO</sub>	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, \text{ I}_{\text{F}} = 0, \text{ E}_{\text{E}} = 0$		

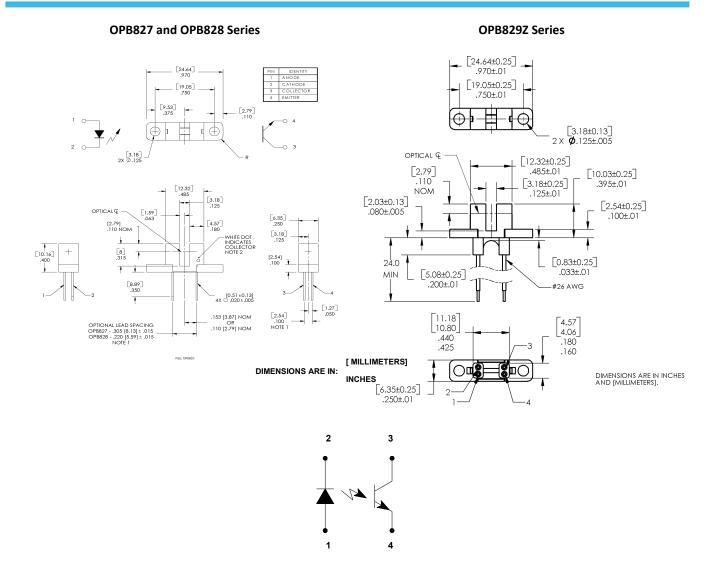
	I <sub>CEO</sub>	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 V, I_F = 0, E_E = 0$	
Cou	Coupled							
	V <sub>CE(SAT)</sub>	Saturation Voltage	-	-	0.6	V	I <sub>C</sub> = 1800 μA, I <sub>F</sub> = 20 mA	
	I <sub>C(ON)</sub>	On-State Collector Current	1800	-	-	μΑ	V <sub>CE</sub> = 0.6 V, I <sub>F</sub> = 20 mA	

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

### OPB827, OPB828, OPB829Z Series





Color/Pin #	Description		Color/Pin #		Description		
Black-2	Cathode		White-3		Collector		
Red-1	Anode		Green-4		Emitter		
Lead Spacing							
OPB827 = 0.305"		OPB828	OPB828 = 0.220"		OPB829 = 24" 26 AWG Wires		

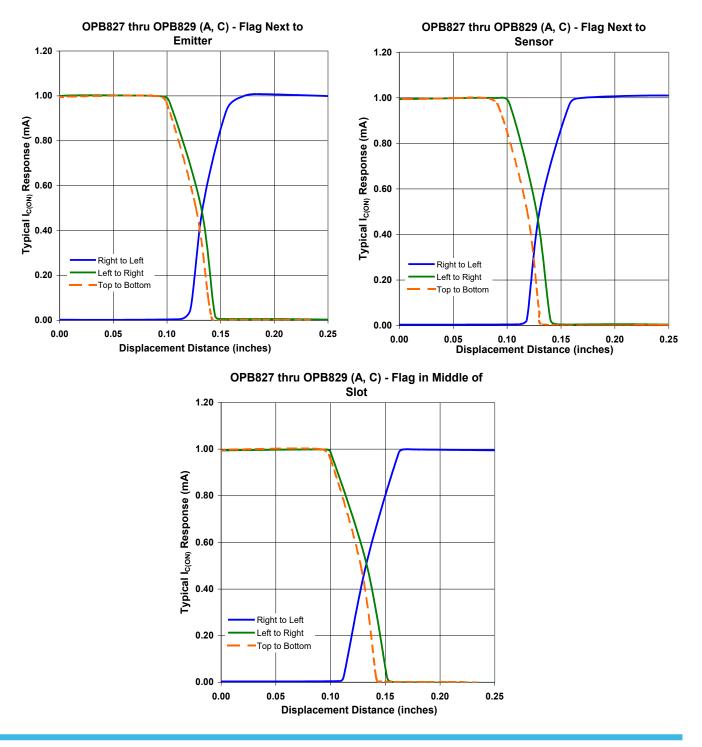
General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

OPB827, OPB828, OPB829Z Series



### Performance



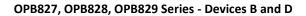
#### OPB827, OPB828, OPB829 Series - Devices A and C

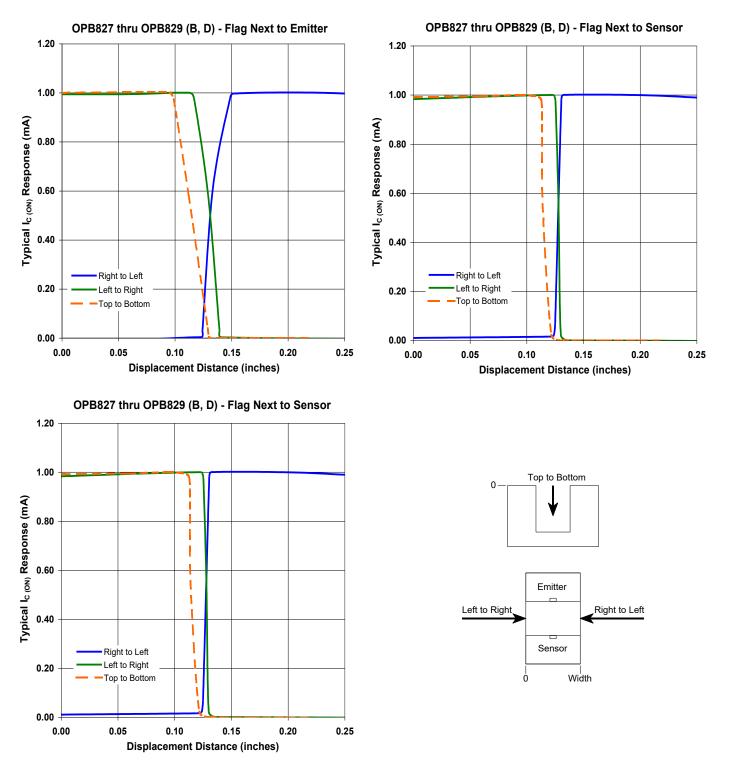
General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

### OPB827, OPB828, OPB829Z Series







General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.